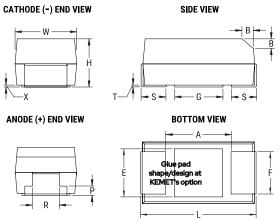


T493B106J016AT6310

T493 HRA, Tantalum, MnO2 Tantalum, HRA, 10 uF, 5%, 16 VDC, SMD, MnO2, Molded, High Reliability, N/A, 3.5 Ohms, 3528, 2.1 mm, 0.8 mm





	-
Click here for the 3D mode	el.

General Information				
Series	T493 HRA			
Dielectric	MnO2 Tantalum			
Style	SMD Chip			
Description	SMD, MnO2, Molded, High Reliability			
Features	High Reliability			
RoHS	Yes			
Termination	Tin			
AEC-Q200	No			
Typical Component Weight	102.3 mg			
Notes	P and R dimensions represents the minimum solderable area of the termination surface entirely below cutout (if one is present).			

Dimensions		
L	3.5mm +/-0.2mm	
W	2.8mm +/-0.2mm	
Н	1.9mm +/-0.2mm	
Т	0.13mm REF	
S	0.8mm +/-0.3mm	
F	2.2mm +/-0.1mm	
A	1.9mm MIN	
В	0.4mm +/-0.15mm	
E	2.2mm REF	
G	1.8mm REF	
Р	0.35mm MIN	
R	1mm REF	
X	0.1mm +/-0.1mm REF	

Packaging Specifications		
Packaging	T&R, 178mm	
Packaging Quantity	2000	

Specifications		
Capacitance	10 uF	
Tolerance	5%	
Voltage DC	16 VDC (85C), 10.72 VDC (125C)	
Temperature Range	-55/+125°C	
Rated Temperature	, 85°C	
Dissipation Factor	6% 120Hz 25C	
Failure Rate	N/A	
ESR	3.5 Ohms (100kHz 25C)	
Ripple Current	156 mA (rms, 100kHz 25C)	
Leakage Current	1.6 uA (5min 25°C)	
Testing and Reliability	10 Cycles Surge Current Testing At -55C And +85C After Weibull	

Statements of suitability for certain applications are based on our knowledge of typical operating conditions for such applications, but are not intended to constitute - and we specifically disclaim - any warranty concerning suitability for a specific customer application or use. This Information is intended for use only by customers who have the requisite experience and capability to determine the correct products for their application. Any technical advice inferred from this Information or otherwise provided by us with reference to the use of our products is given gratis, and we assume no obligation or liability for the advice given or results obtained.

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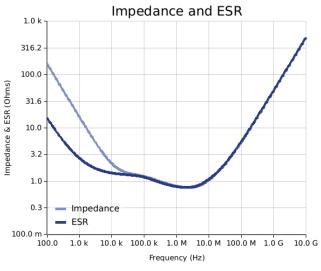


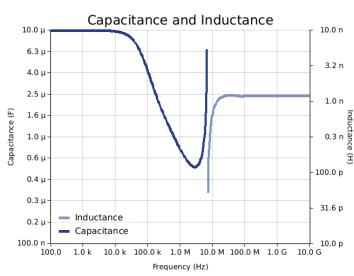


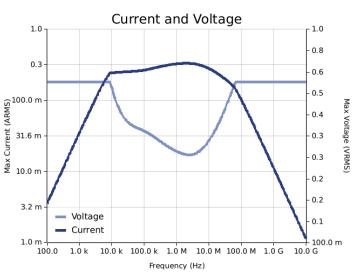
T493 HRA, Tantalum, MnO2 Tantalum, HRA, 10 uF, 5%, 16 VDC, SMD, MnO2, Molded, High Reliability, N/A, 3.5 Ohms, 3528, 2.1 mm, 0.8 mm

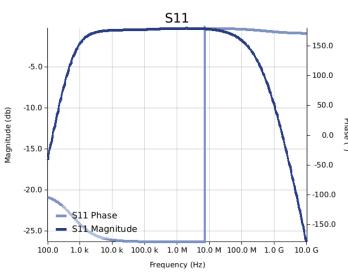
Simulations

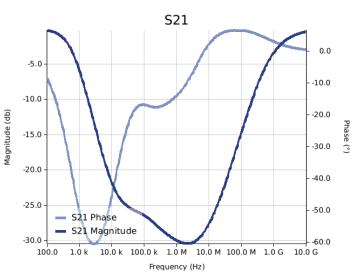
For the complete simulation environment please visit K-SIM.











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T493B106J016AT6310

T493 HRA, Tantalum, MnO2 Tantalum, HRA, 10 uF, 5%, 16 VDC, SMD, MnO2, Molded, High Reliability, N/A, 3.5 Ohms, 3528, 2.1 mm, 0.8 mm

These are simulations.

This is not a specification!

The responses shown represent the typical response for each part type. Specific responses may vary, depending on manufacturing variation affects of all parameters involved, including the specified tolerances applied to capacitance and unspecified variations of ESR, ESL, and leakage resistance.

The responses shown do not represent a specified or implied maximum capability of the device for all applications.

- The ESR used for ripple "Ripple Current/Voltage vs. Frequency" plots is the ESR at ambient temperature.

- The ESR in the "Temperature Rise vs. Ripple Current" plots is adjusted to each incremental temperature rise before the power and ripple current is calculated. The effects shown herein are based on measured data from a multiple part sample of the parts in question.

 Ripple capability of this device will be factored by thermal resistance (Rth) created by circuit traces (addi affects of all parameters involved, including the specified tolerances applied to capacitance and unspecified variations of ESR, ESL, and leakage resistance.

 The peak voltages generated in the "Temperature Rise vs. Combined Ripple Currents" plot are calculated for each frequency and are not combined with voltages
- generated at any other harmonics.

 Please consult with the catalog or field applications engineer for maximum capability of the device in specific applications.

All product information and data (collectively, the "Information") are subject to change without notice.

KEMET K-SIM is designed to simulate behavior of components with respect to frequency, ambient temperature, and DC bias levels. The responses shown represent the typical response for each part type. Specific responses may vary, depending on manufacturing variation effects of all parameters involved, including the specified tolerances applied to capacitance and unspecified variations of ESR, ESL, and leakage resistance.

All Information given herein is believed to be accurate and reliable, but is presented without guarantee, warranty, or responsibility of any kind, expressed or implied. Statements of suitability for certain applications are based on our knowledge of typical operating conditions for such applications, but are not intended to constitute – and we specifically disclaim – any warranty concerning suitability for a specific customer application or use. This Information is intended for use only by customers who have the requisite experience and capability to determine the correct products for their application. Any technical advice inferred from this Information or otherwise provided by us with reference to the use of our products is given gratis, and we assume no obligation or liability for the advice given or results obtained.

If you have any questions please contact K-SIM.

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